

ECE 340 Lecture3

Semiconductor Electronics

Spring 2022

10:00-10:50am

Professor Umberto Ravaioli

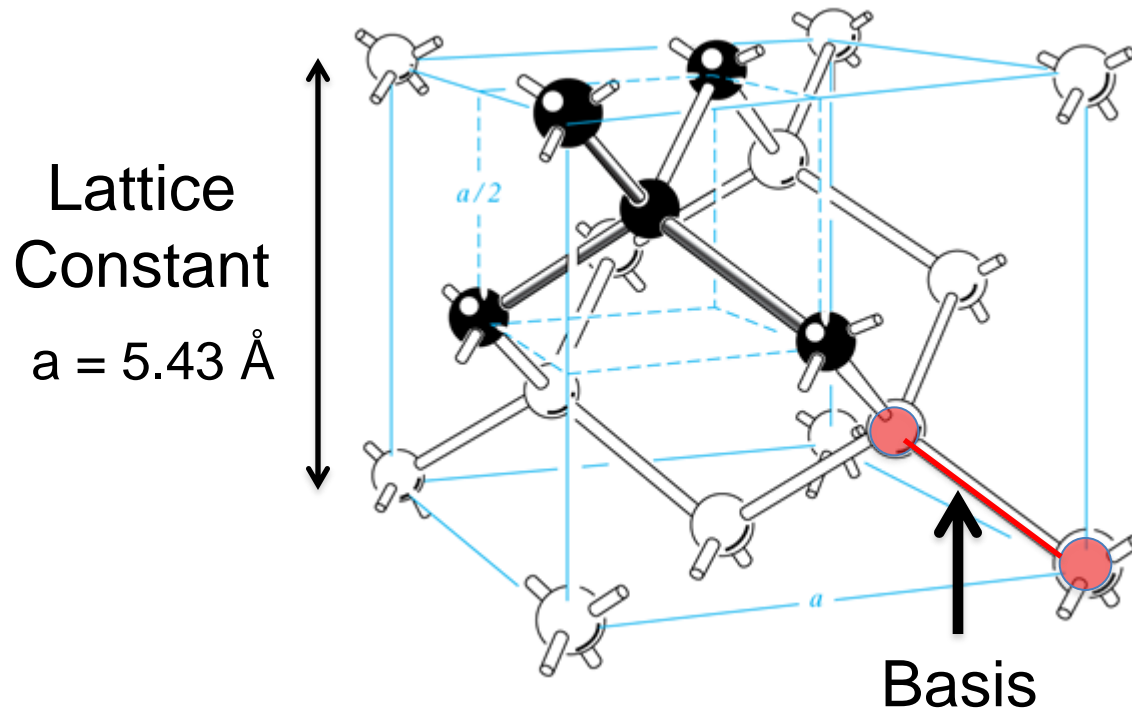
Department of Electrical and Computer Engineering

2062 ECE Building

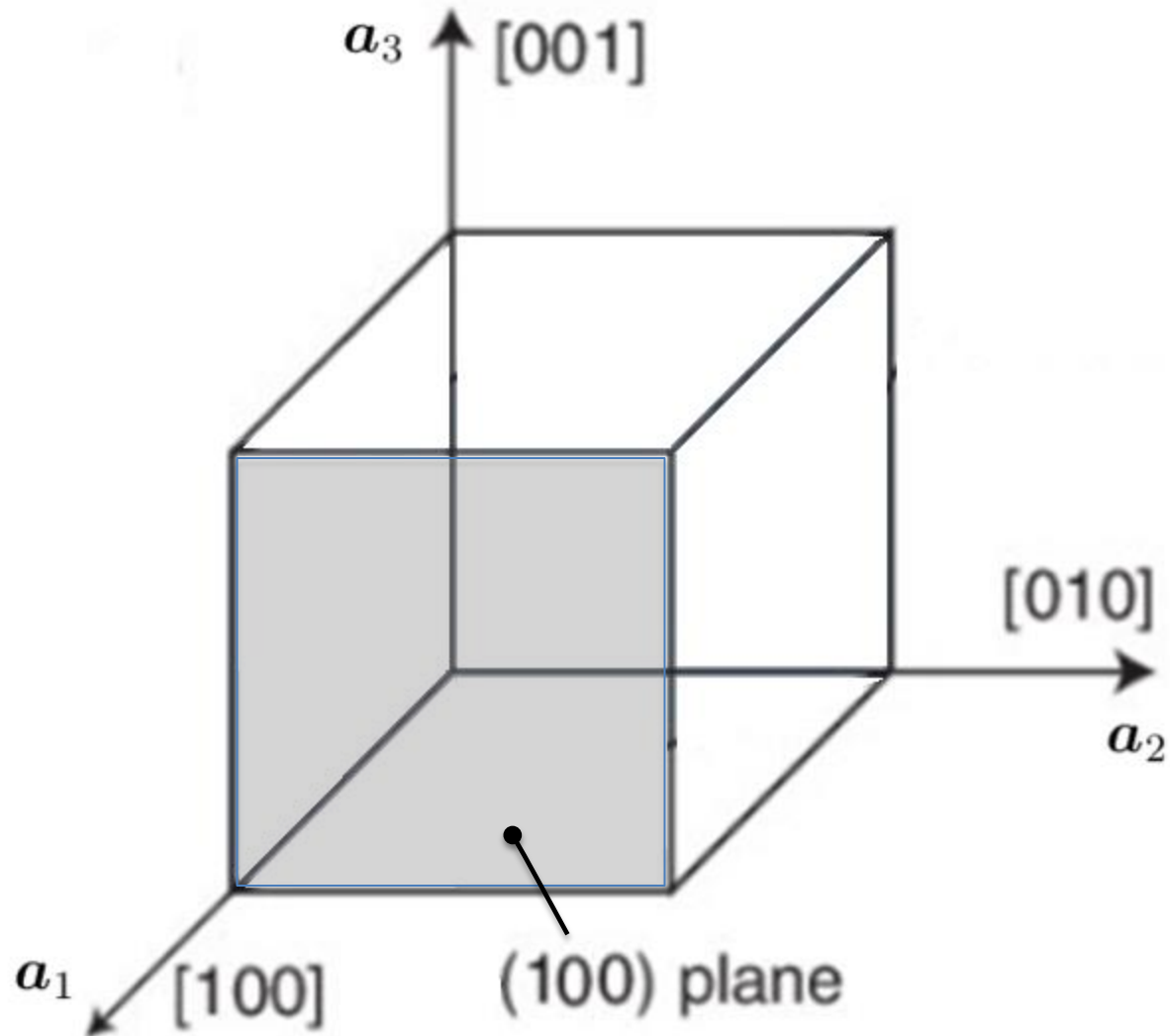
Today's Discussion

- More on crystals
- Bonding Forces
- Energy Bands

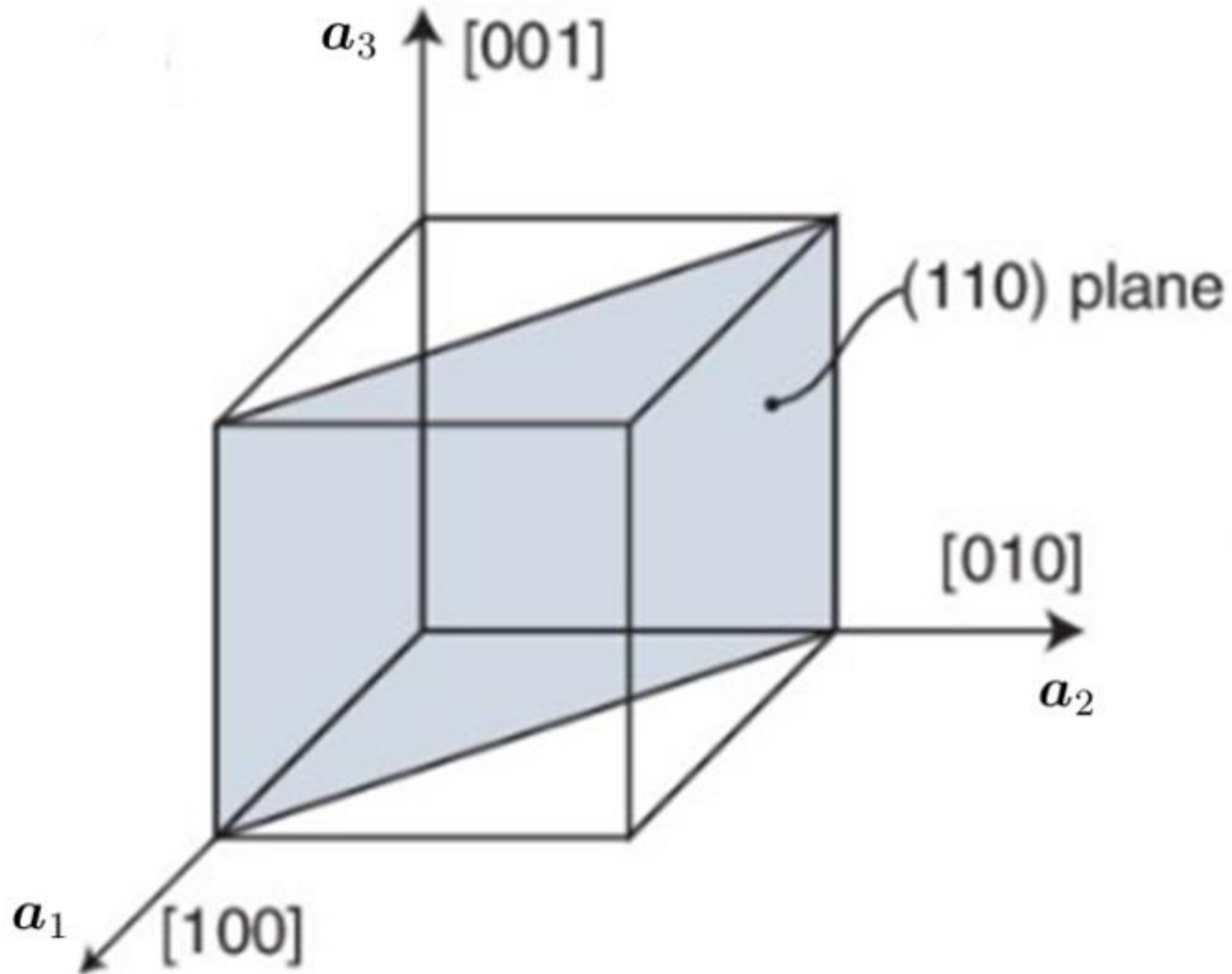
Silicon



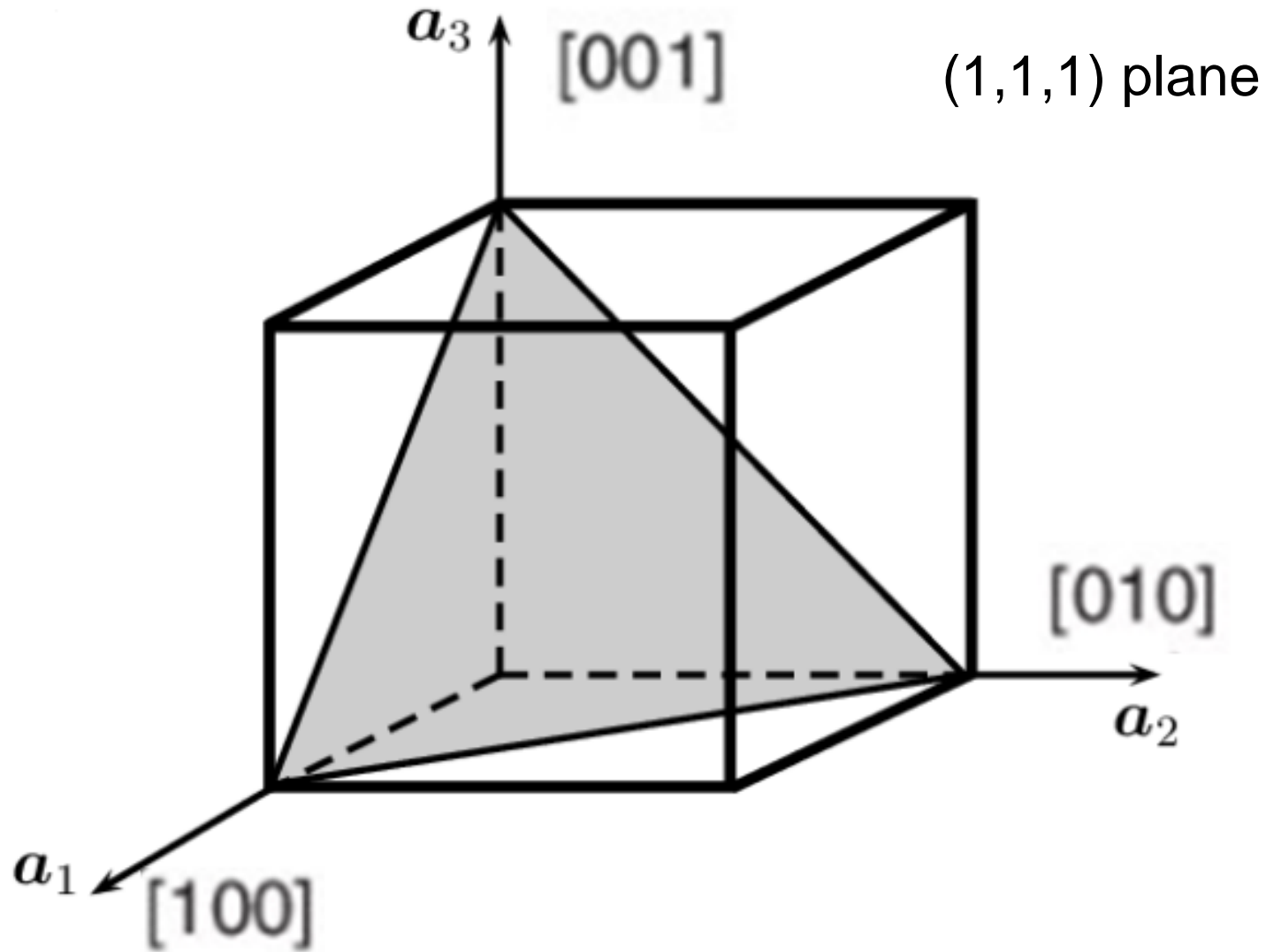
Miller indices



Miller indices



Miller indices



Miller indices

A crystal plane: (hkl)

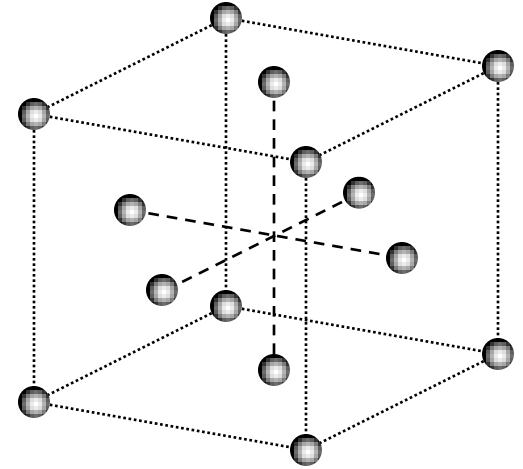
Family of equivalent planes: $\{hkl\}$

Crystal direction: $[hkl]$

(normal to plane (hkl) in a cubic lattice)

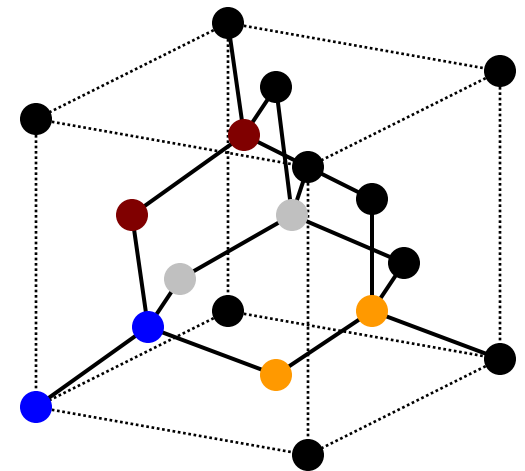
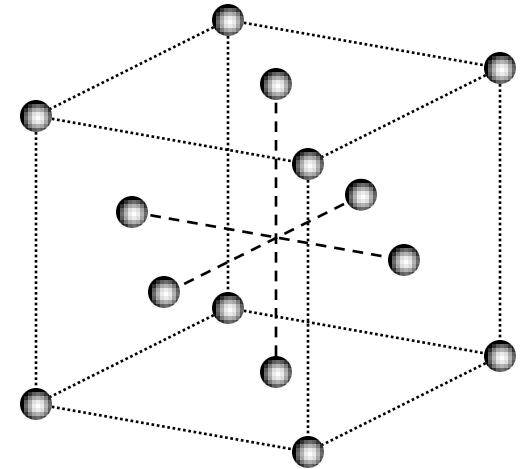
Let's get to know Silicon better (1)

- How many atoms in the unit cell?
 - Let's look at the FCC lattice first



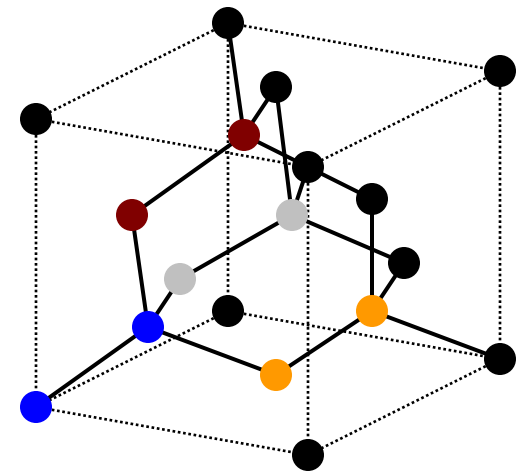
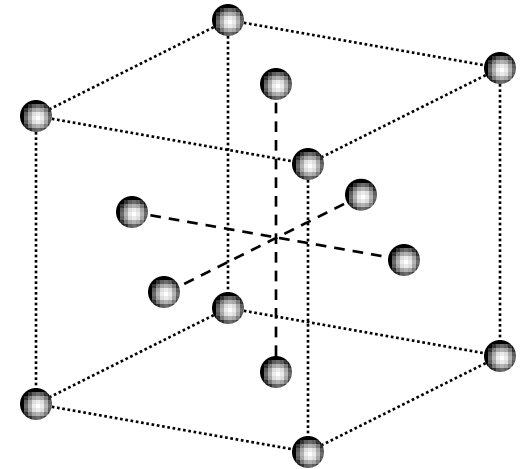
Let's get to know Silicon better (1)

- How many atoms in the unit cell?
 - Let's look at the FCC lattice first
- **4 ATOMS PER CELL**
- Now, add the second sub-lattice of the diamond lattice

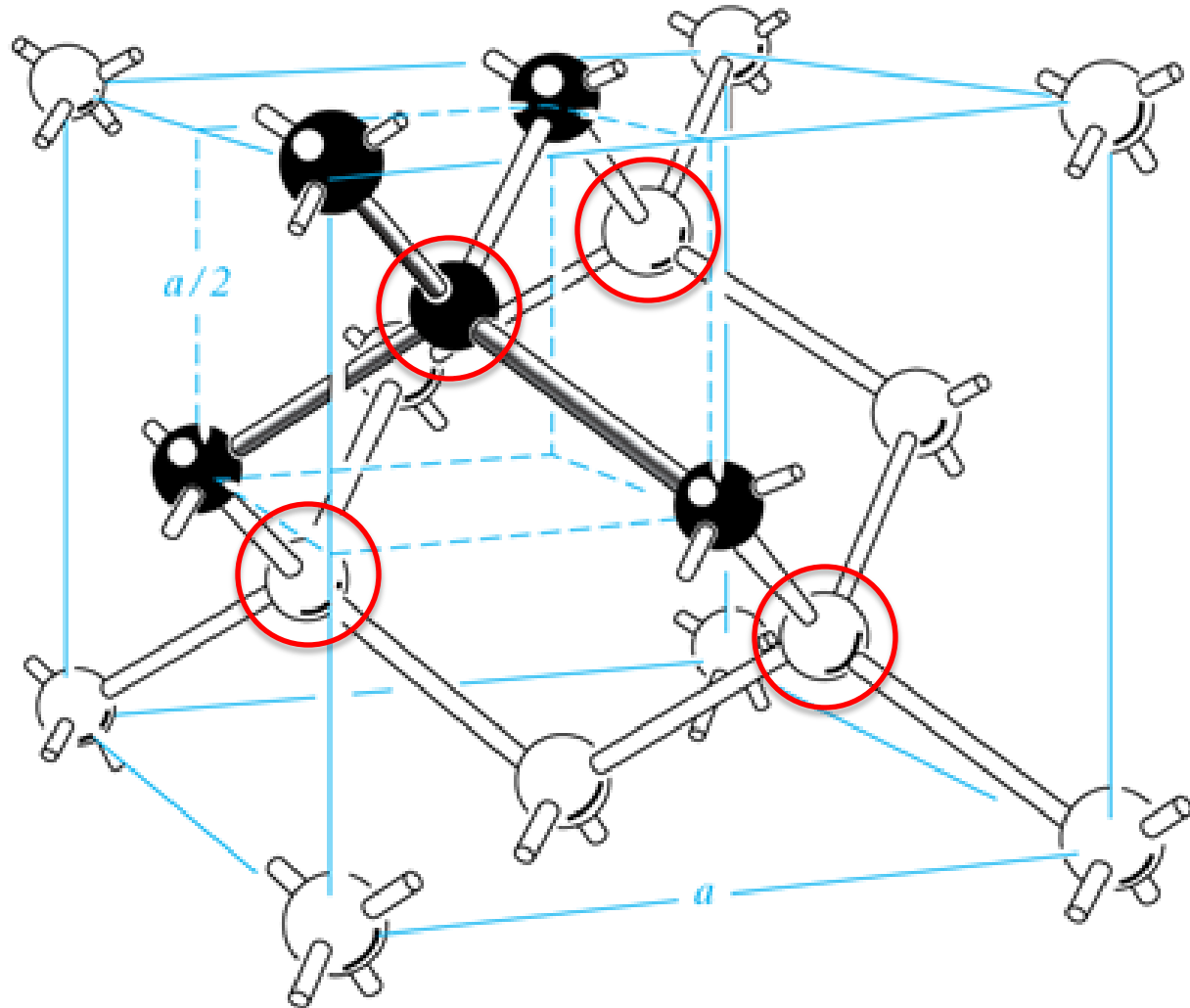


Let's get to know Silicon better (1)

- How many atoms in the unit cell?
 - Let's look at the FCC lattice first
- **4 ATOMS PER CELL**
- Now, add the second sub-lattice of the diamond lattice
- **8 ATOMS PER CELL**

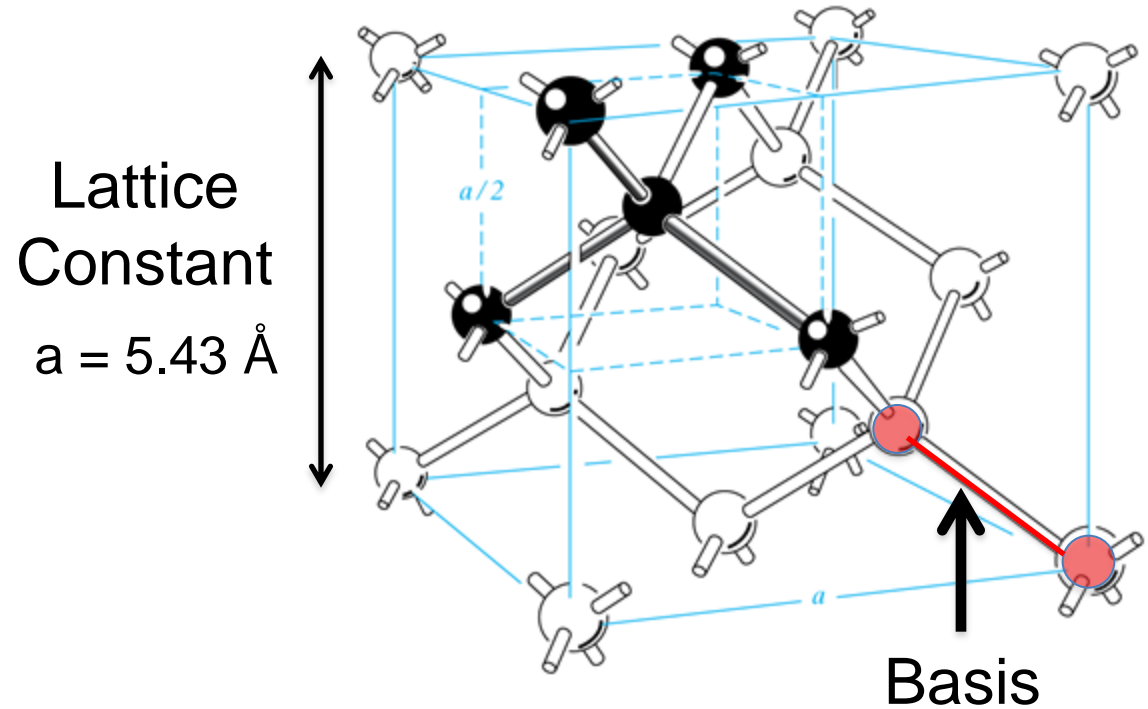


Let's get to know Silicon better (1)



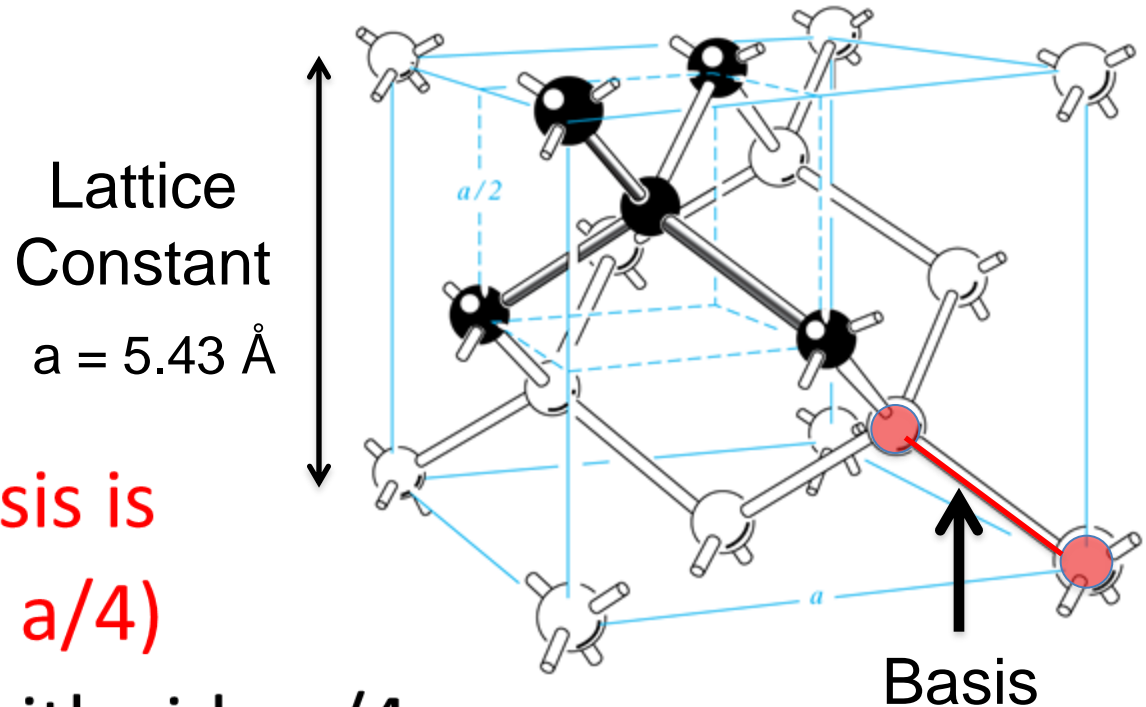
Let's get to know Silicon better (2)

- What is the distance between nearest neighbors?



Let's get to know Silicon better (2)

- What is the distance between nearest neighbors?



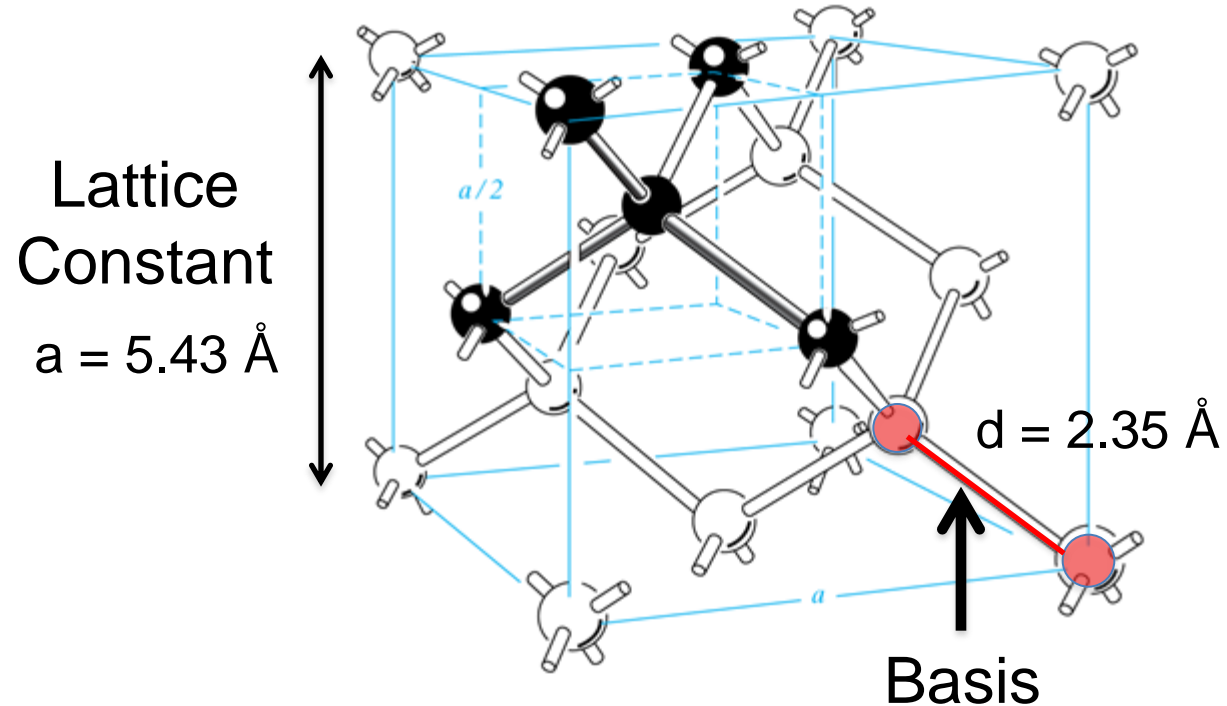
Second atom in basis is offset by $(a/4, a/4, a/4)$

Diagonal of cube with side $a/4$

$$d = \frac{\sqrt{3}a}{4} = \frac{1.732 \times 5.43}{4} = 2.35 \text{ \AA}$$

Let's get to know Silicon better (3)

- What is the packing fraction of Silicon?



Let's get to know Silicon better (3)

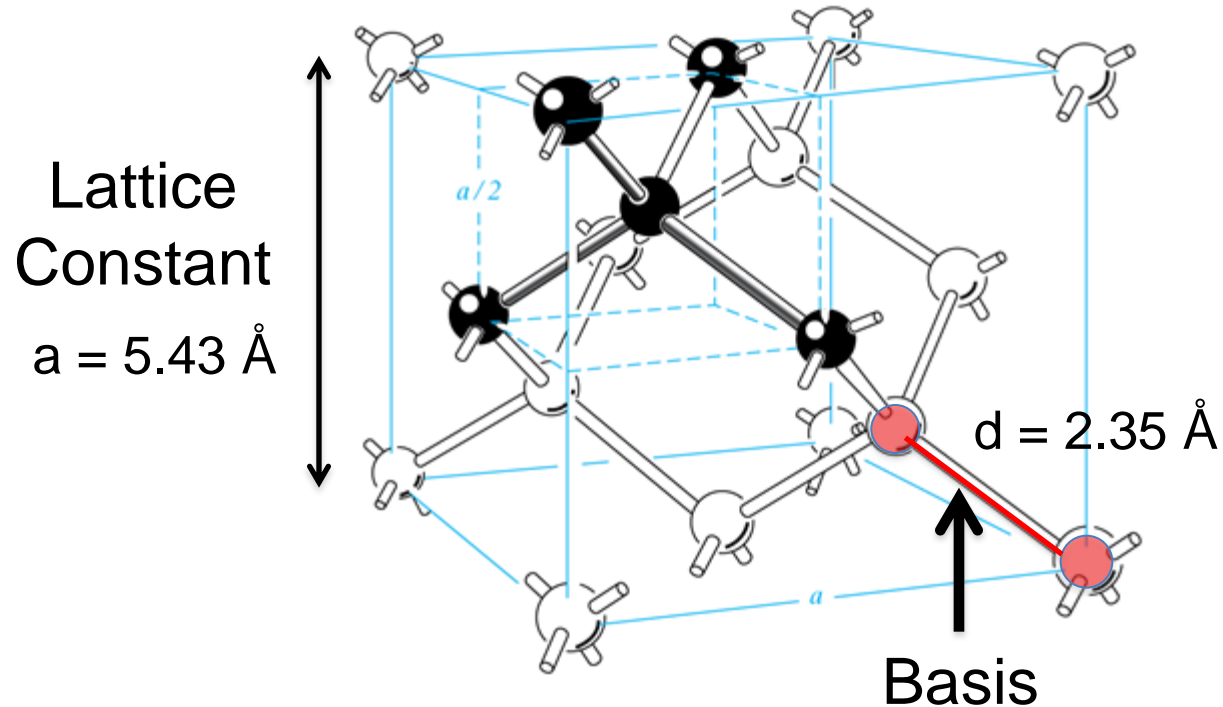
- What is the packing fraction of Silicon?

Volume of
unit cell = a^3
= 160.1 \AA^3

Volume of atom
(assume a sphere)

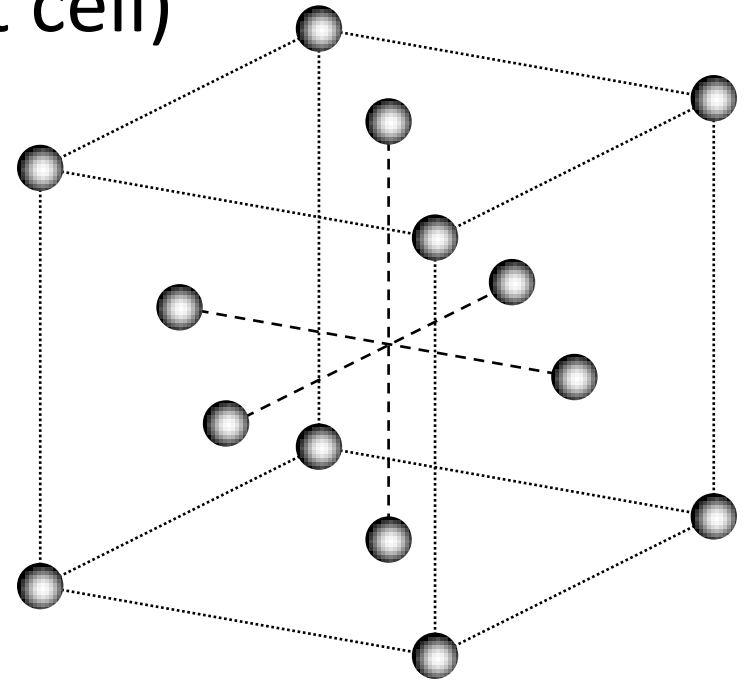
$$\frac{4}{3} \pi \left(\frac{d}{2} \right)^3 = 6.8 \text{ \AA}^3$$

Packing fraction = $(8 \times 6.8) / 160.1 = 0.34 = 34\%$



Let's get to know Silicon better (4)

- What is the packing fraction of a simple fcc lattice? (remember: 4 atoms per unit cell)



Let's get to know Silicon better (4)

- What is the packing fraction of a simple fcc lattice?
(remember: 4 atoms per unit cell)

Volume of unit cell = a^3

Nearest neighbor distance =

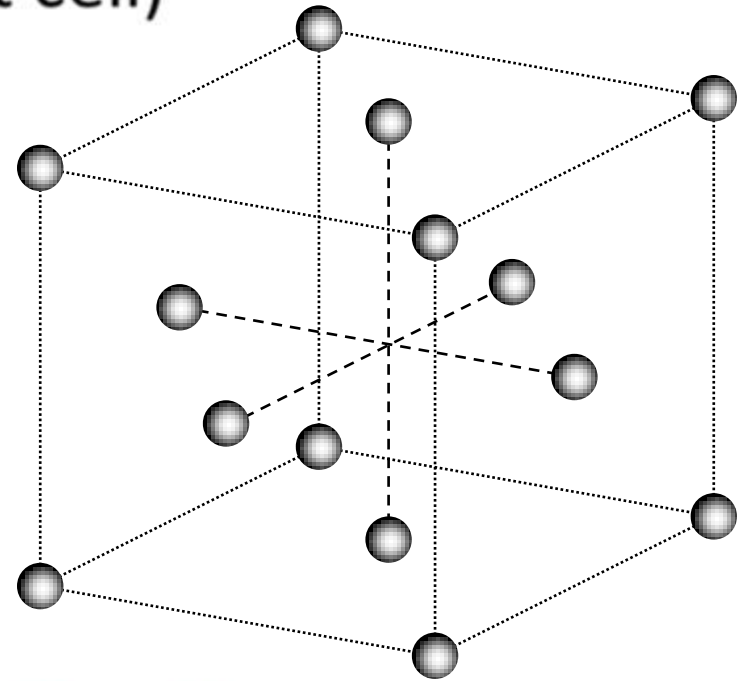
$$d = \frac{a}{2} \sqrt{2}$$

Volume of atom

$$\frac{4}{3} \pi \left(\frac{a}{4} \sqrt{2} \right)^3 = 0.185 a^3$$

Packing fraction = $(4 \times 0.185) a^3 / a^3 = 0.74 = 74\%$

Interesting... that's more than twice than for diamond lattice.



Packing fractions for cubic lattices

- Face-Centered Cubic

$$\sqrt{2} \frac{\pi}{6} = 0.74$$

- Body-Centered Cubic

$$\sqrt{3} \frac{\pi}{8} = 0.68$$

- Simple Cubic

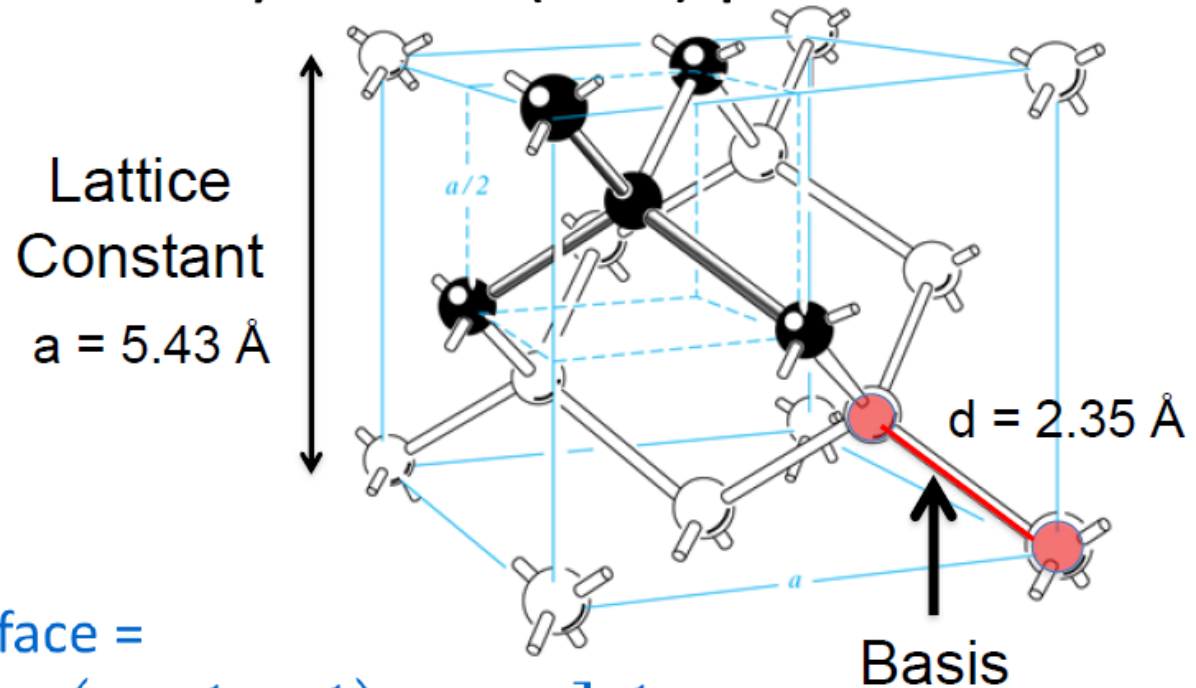
$$\frac{\pi}{6} = 0.52$$

- Diamond Lattice

$$\sqrt{3} \frac{\pi}{16} = 0.34$$

Let's get to know Silicon better (5)

- What is the areal density of the (100) plane?



Areal Density =

= # Atoms on face / Area face =

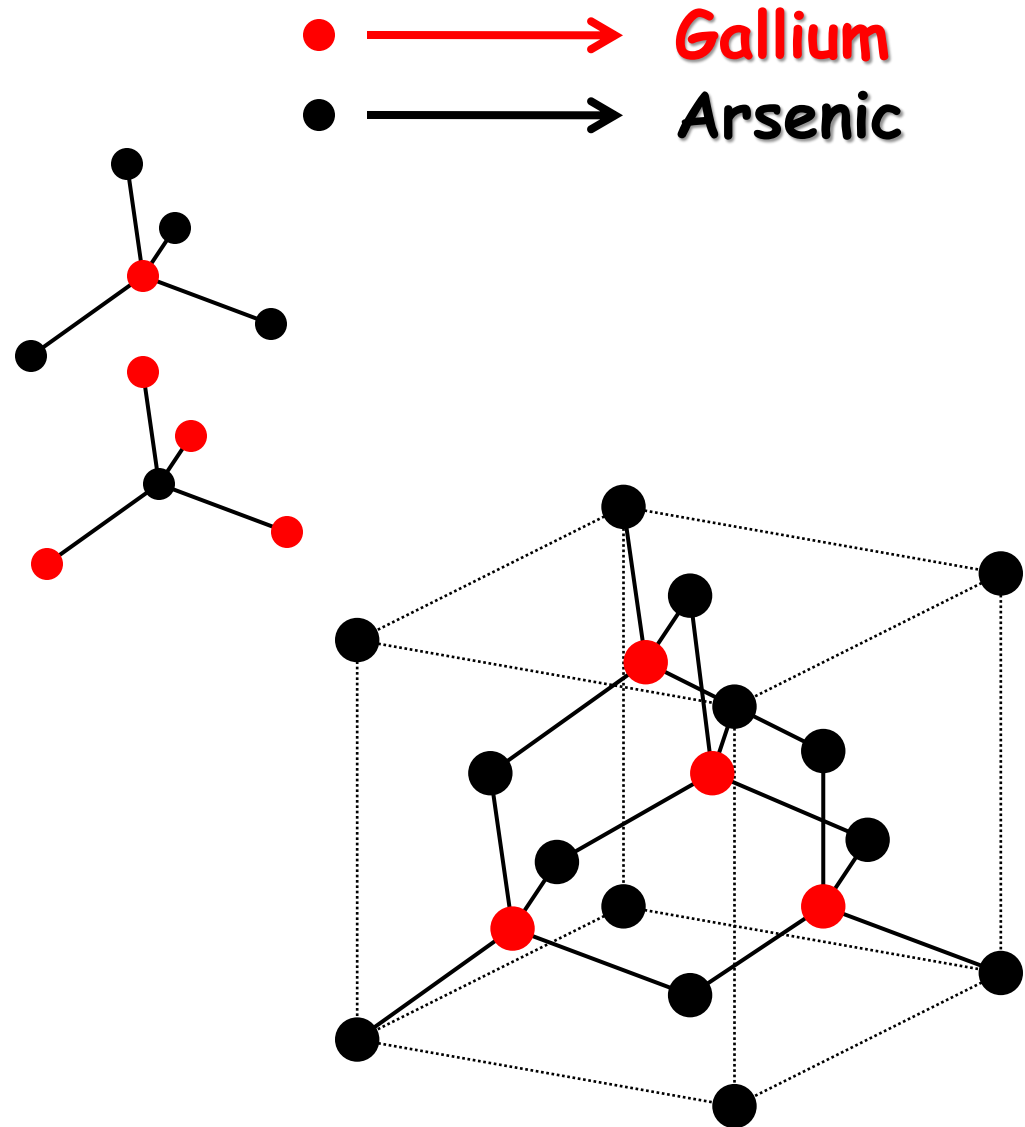
$$= \left[\left(4 \times \frac{1}{8} + \frac{1}{2} \right)_{\text{above surface}} + \left(4 \times \frac{1}{8} + \frac{1}{2} \right)_{\text{below surface}} \right] \frac{1}{a^2} = 2/a^2$$

$$= 6.78 \times 10^{18} \text{ m}^{-2} = 6.78 \times 10^{14} \text{ cm}^{-2}$$

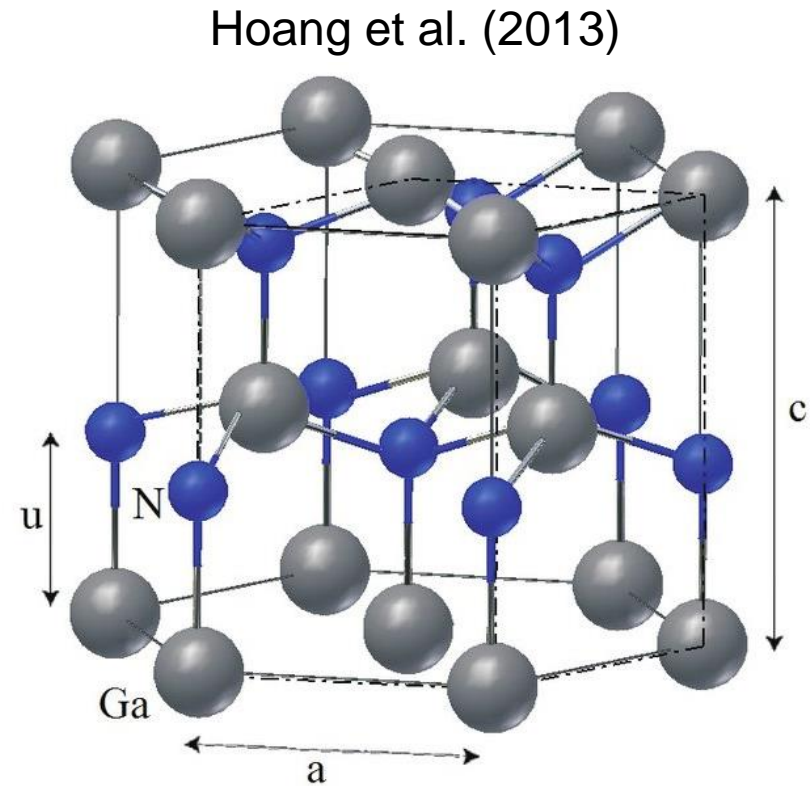
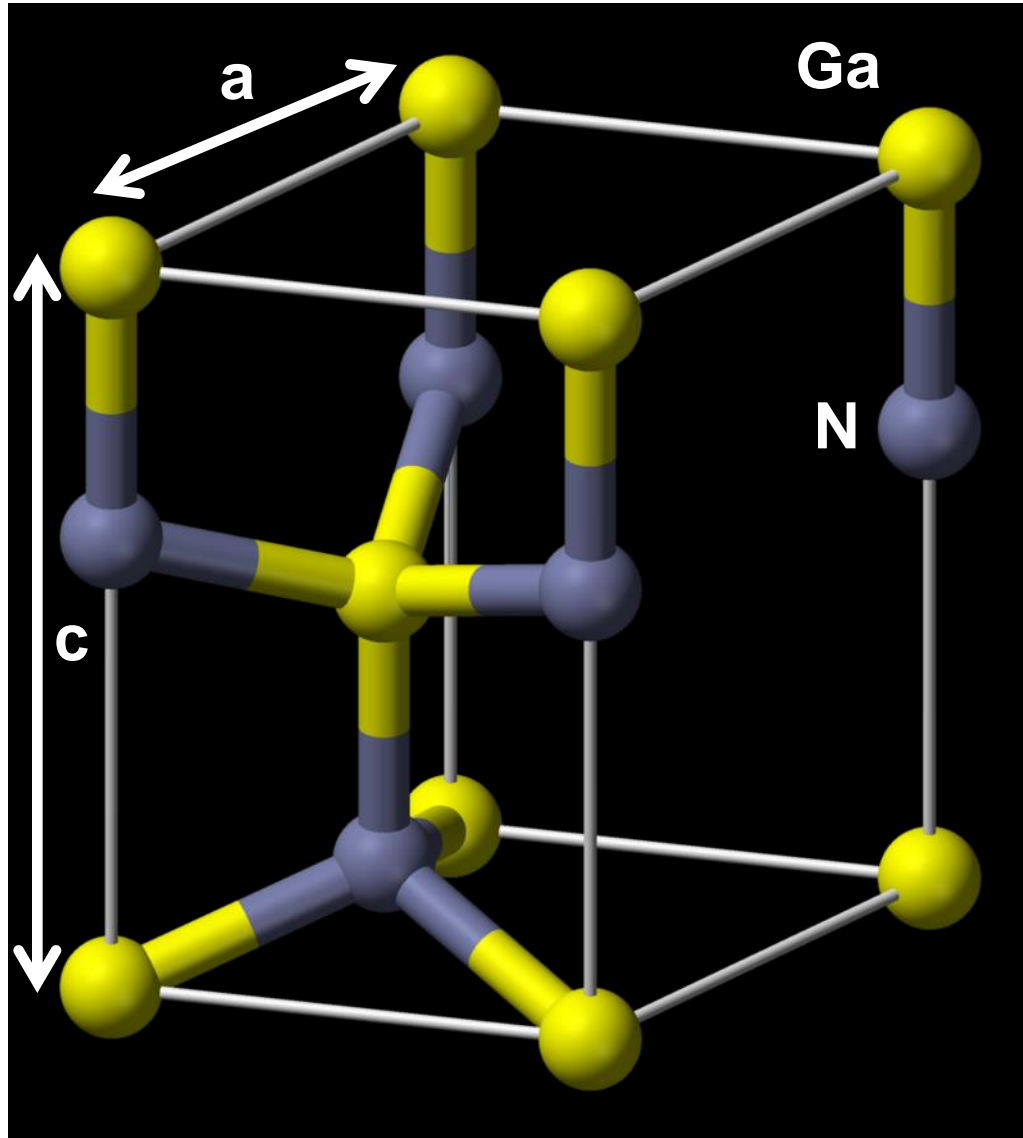
Compound Semiconductors

- Many compound semiconductors such as Gallium Arsenide (GaAs) exhibit the **zincblende** crystal structure.

– The atomic configuration is the same as **diamond**.

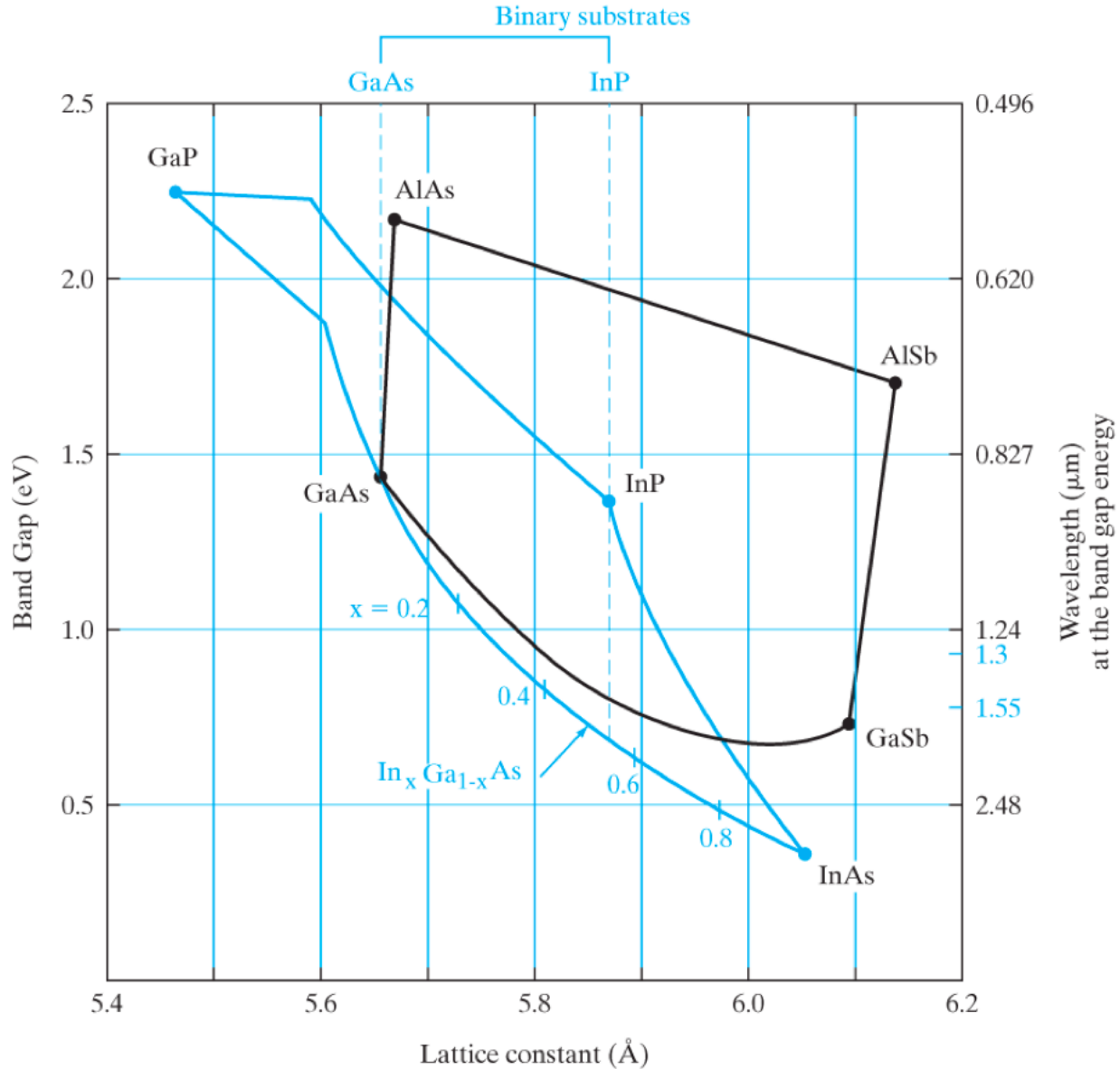


Wurtzite Structure



Adapted from Wikipedia, "Wurtzite"

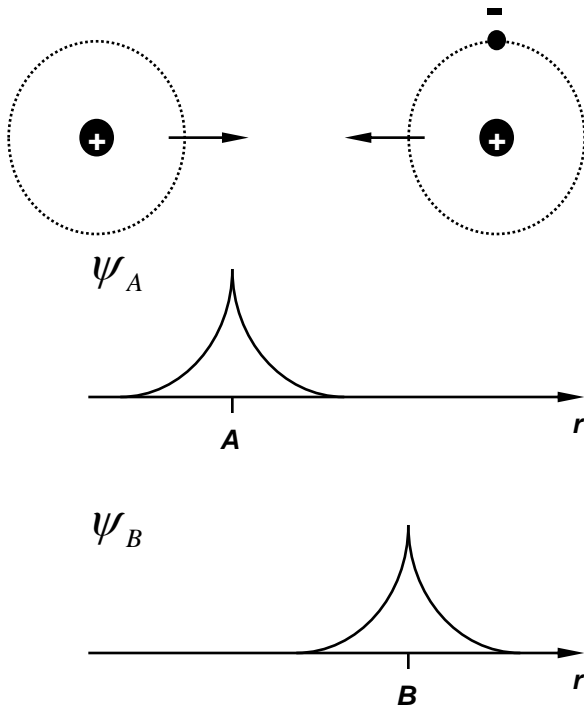
Important Material Systems



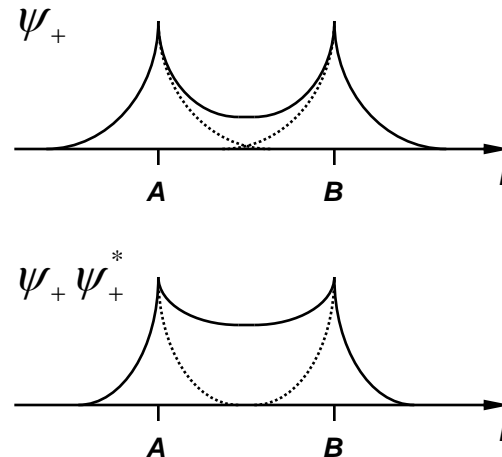
Bonding Forces and Energy Bands

Bonding in Hydrogen atom

- Hydrogen – Consider the case of two atoms A and B with ground state wavefunctions: The resulting molecule is a superposition of the two atomic wavefunctions



$$\psi_{\pm} = \psi_A \pm \psi_B$$

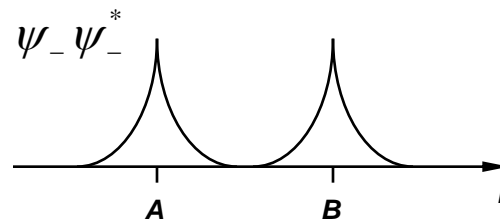
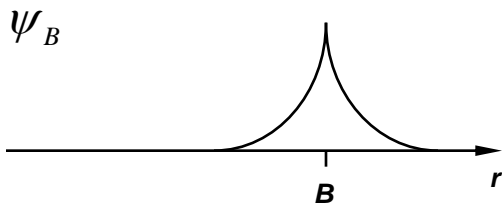
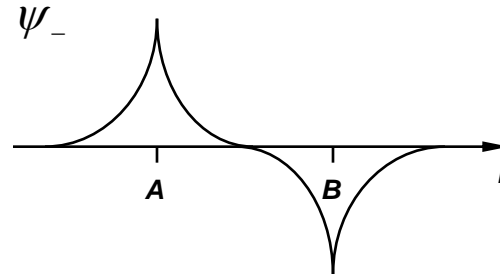
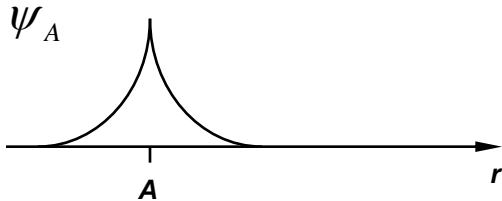


Symmetric State

Bonding in Hydrogen atom

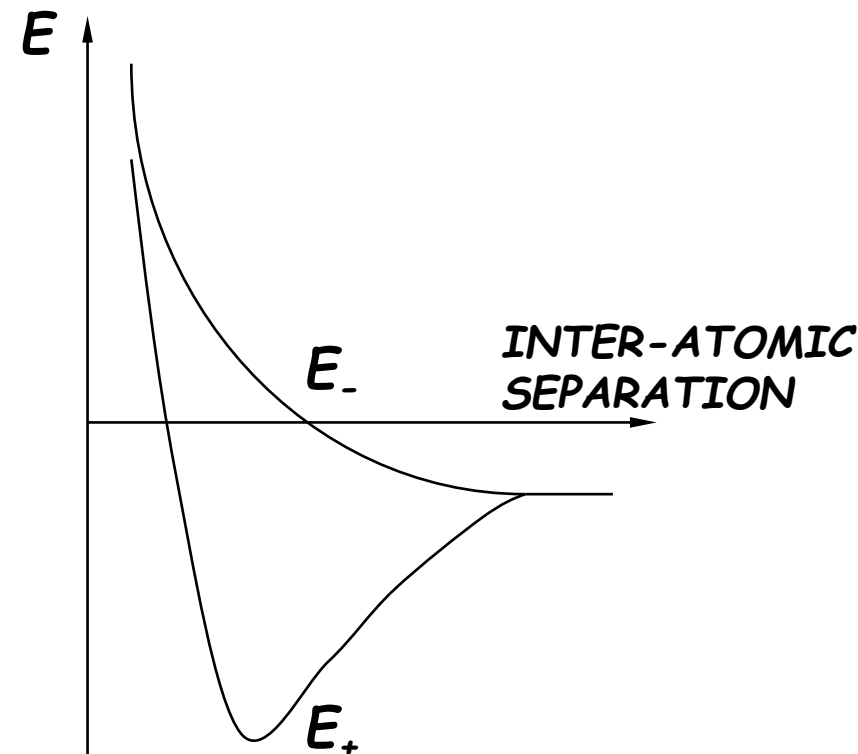
But another combination of wavefunctions exists.

- Antisymmetric wavefunction gives less probability of finding the electron between the two atoms.
 - The symmetric state lies lower in energy.
 - The symmetric state is referred to as the bonding state and the antisymmetric state is referred to as the anti-bonding state.



Bonding in Hydrogen atom

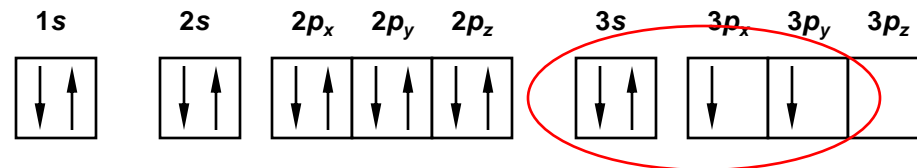
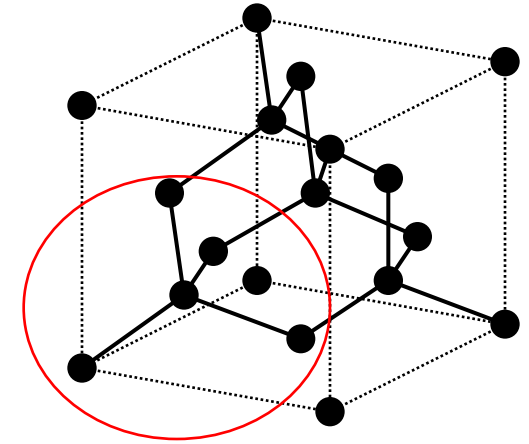
- There is no minimum present in the anti-bonding state indicating the absence of a stable molecular state.
- In the bonding state there is a minimum: stable molecular state



- WHEN ATOMS ARE FAR APART BONDING AND ANTI-BONDING STATES ARE EQUAL IN ENERGY.
- AS THE INTER-ATOMIC SEPARATION IS REDUCED HOWEVER THE ENERGY OF THE BONDING STATE DECREASES FASTER THAN THAT OF THE ANTI-BONDING STATE.
- THE EXISTENCE OF A MINIMUM ENERGY IN THE BONDING STATE DETERMINES THE EQUILIBRIUM SEPARATION OF THE HYDROGEN ATOMS IN THE MOLECULE .

Crystal Bonding

- Each atom shares bonds with 4 other atoms.
- Silicon bonds are covalent, but compound semiconductors have a mix of ionic and covalent bonds.



When silicon atoms **COMBINE** to form a crystal the *s*- and *p*- orbitals **HYBRIDIZE** to form so-called sp^3 ORBITALS that are mixtures of the *s*- and *p*-orbitals.



s-ORBITAL



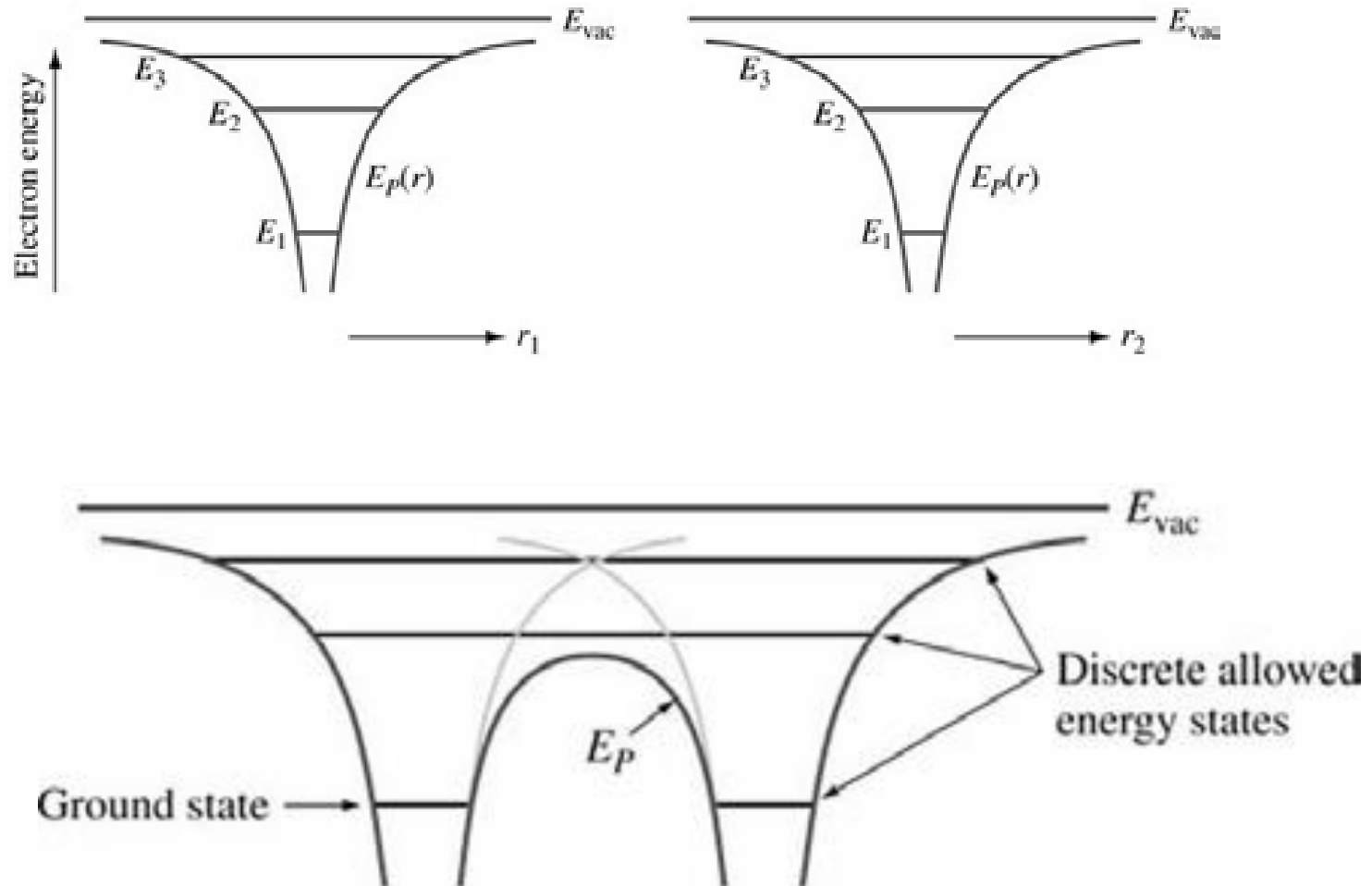
p-ORBITAL



sp^3 -ORBITAL

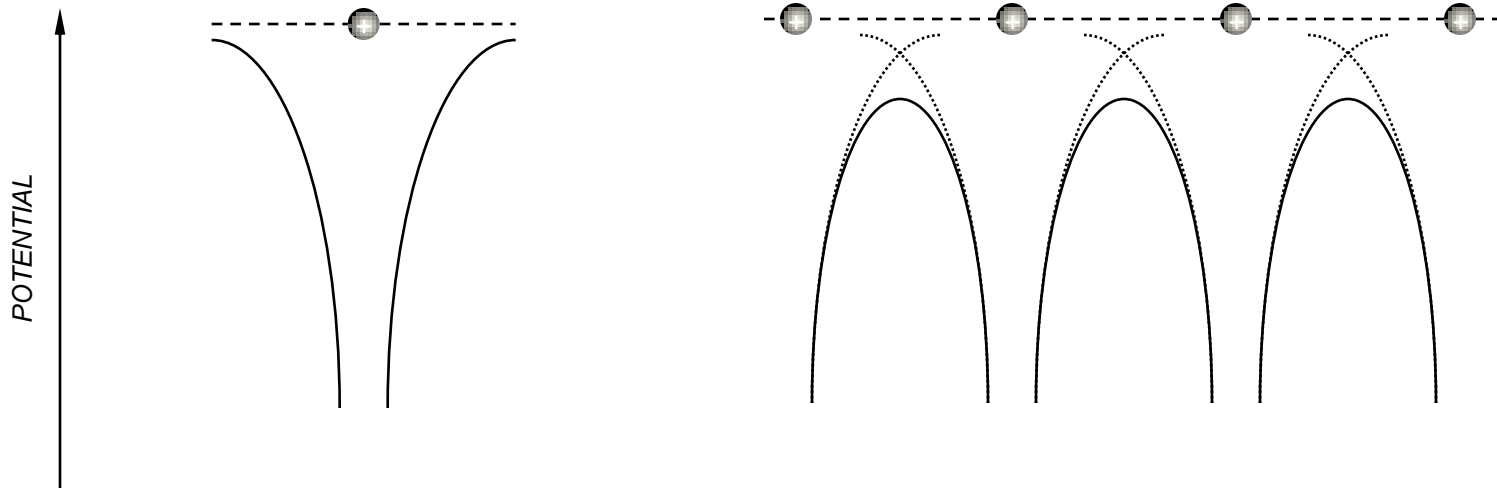
Crystal Bonding

Bring atoms together, the wavefunctions begin to overlap.



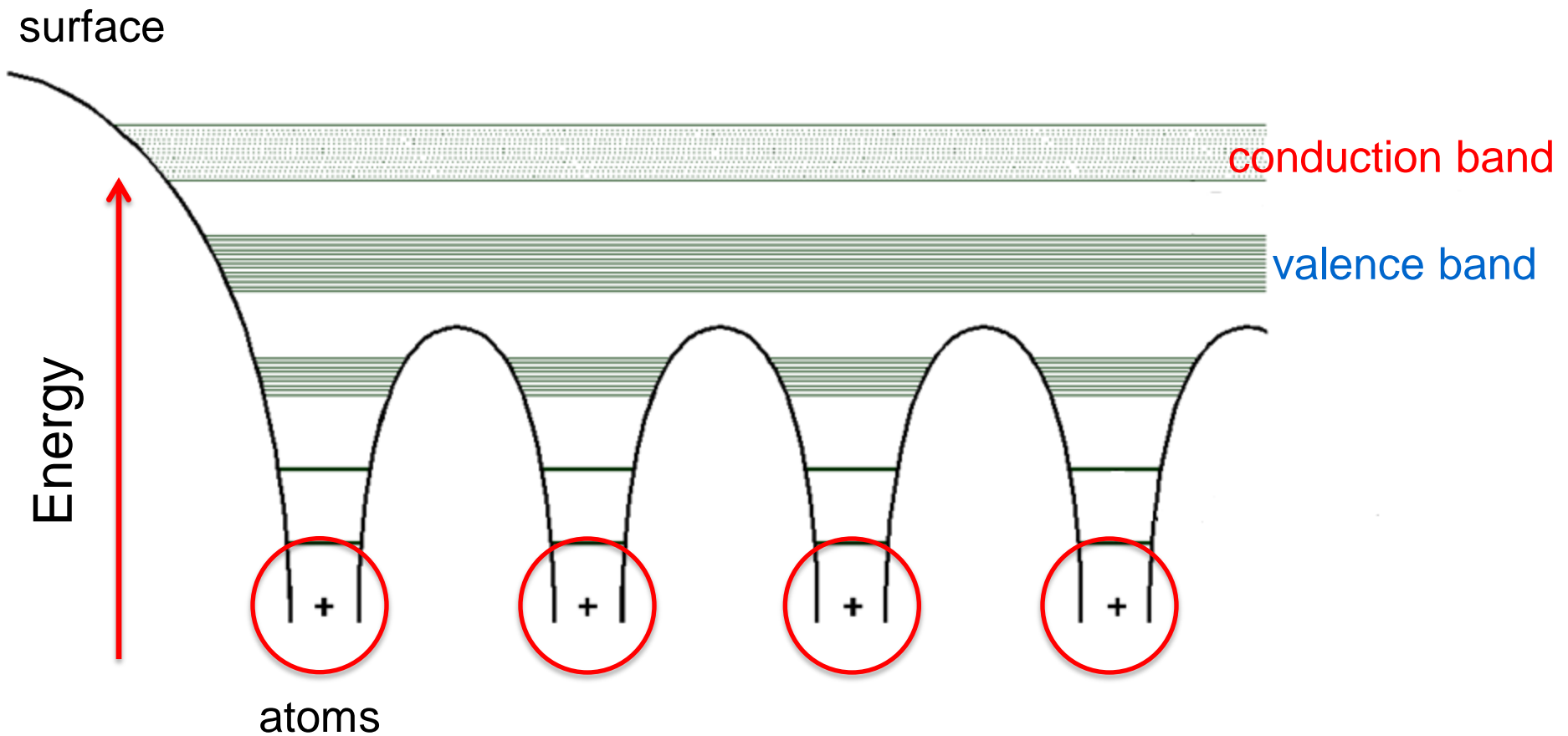
Energy Band Formation

IN A SINGLE ATOM ELECTRONS ARE TRAPPED IN A POTENTIAL WELL

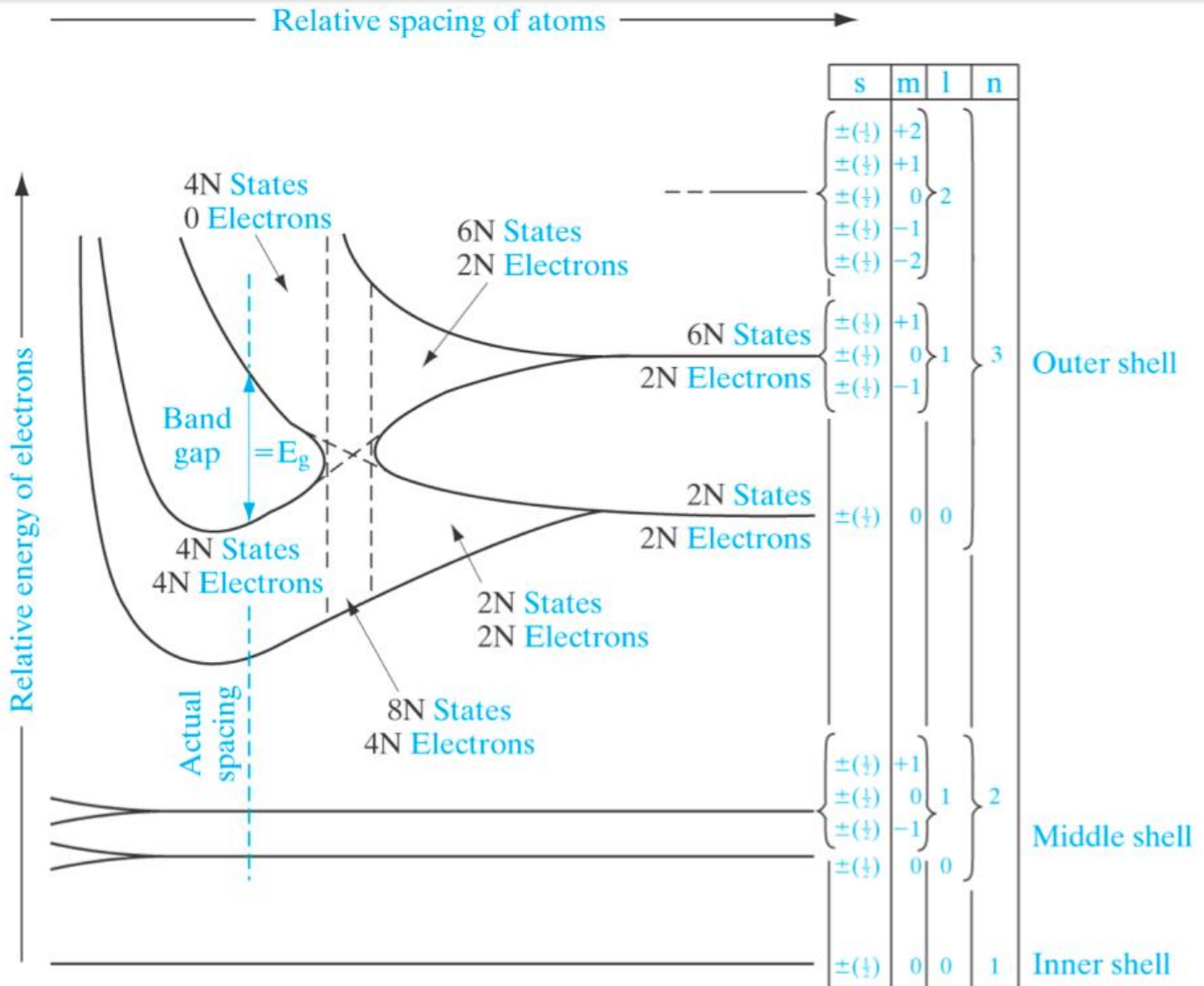


WHEN MANY ATOMS COMBINE AND FORM A CRYSTAL THE ATOMIC POTENTIALS OVERLAP GIVING RISE TO A PERIODIC VARIATION

Energy Band Formation

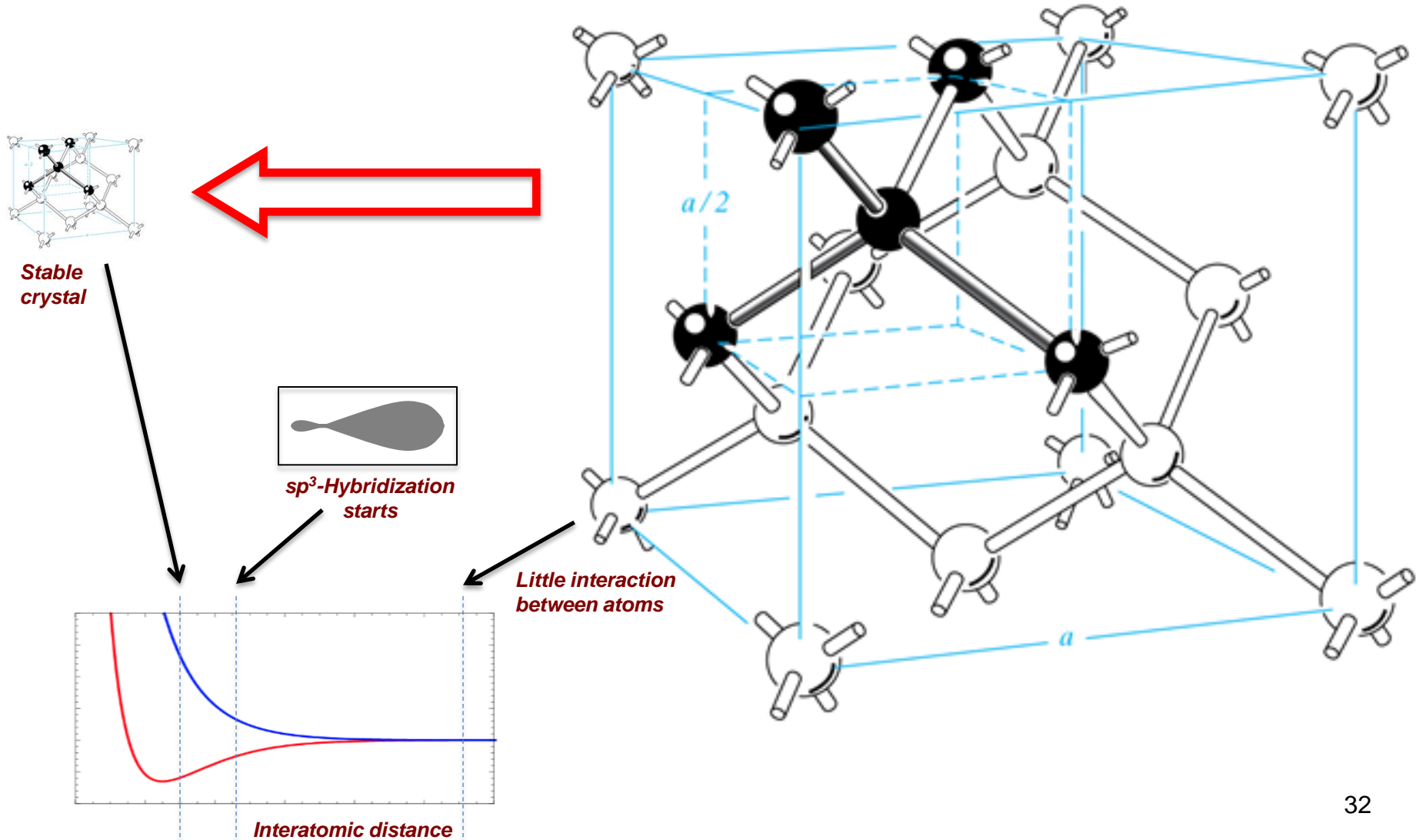


Energy Band Formation



Gedanken Experiment

Imagine you start with $a \gg$ and then shrink down to exact size



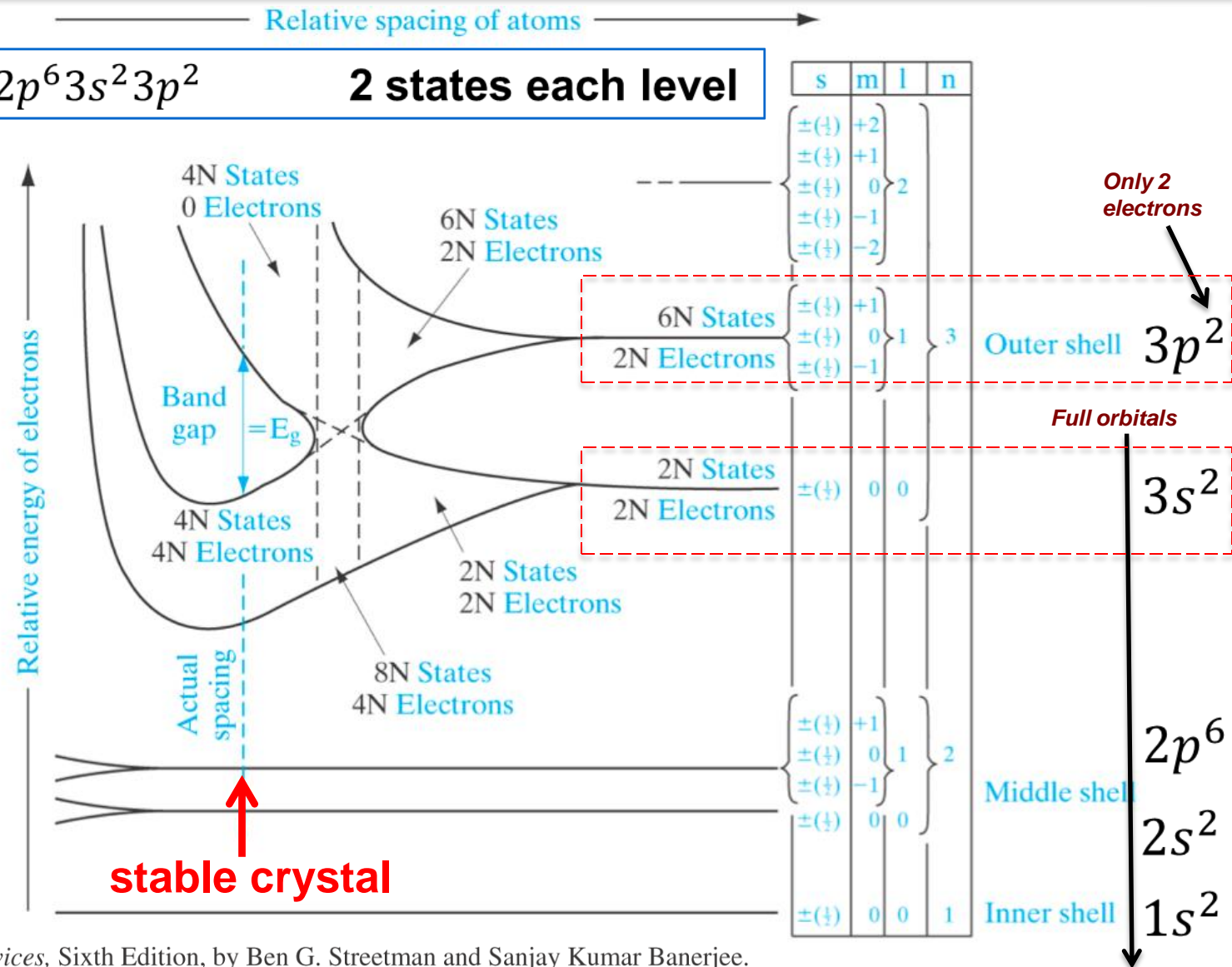
Energy Bands Formation

Silicon – $1s^2 2s^2 2p^6 3s^2 3p^2$

2 states each level

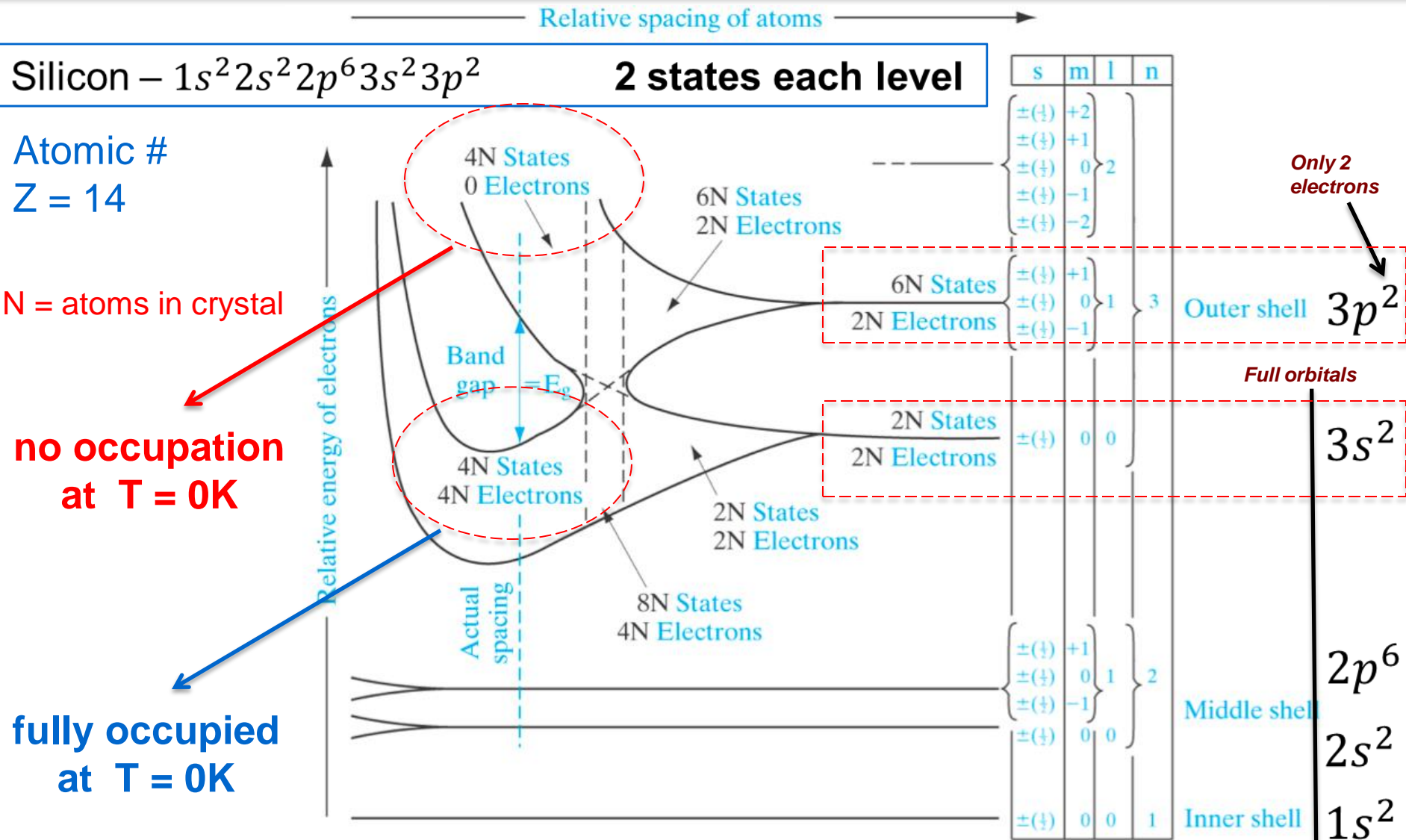
Atomic #
 $Z = 14$

$N =$ atoms in crystal



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Energy Bands Formation



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Energy Band Formation

